

Excellent Integrated System Limited

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Vishay Semiconductor/Diodes Division VT80L45PW-M3/4W

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VT80L45PW-M3/4W - DIODE SCHOTTKY 80A 45V TMBS

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Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.23$ V at $I_F = 5$ A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 40 A			
V _{RRM}	45 V			
I _{FSM}	450 A			
V_F at I_F = 40 A (T_A = 125 °C)	0.43 V			
T _J max.	150 °C			
Package	TO-3PW			
Diode variations	Dual common cathode			

FEATURES



ROHS COMPLIANT

VT80L45PW

- · Low forward voltage drop, low power losses
- High efficiency operation

Trench MOS Schottky technology

- Solder dip 275 °C max. 10 s, per JESD 22-B106
 FREE
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VT80L45PW	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	45	V		
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	80	A	
	per diode		40		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	450	A	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	

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VT80L45PW

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \ ^{\circ}C$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.36	-	V	
	I _F = 20 A			0.43	-		
	I _F = 40 A			0.50	0.58		
	I _F = 5 A	T _A = 125 °C		0.23	-		
	I _F = 20 A			0.34	-		
	I _F = 40 A			0.43	0.52		
Reverse current per diode	N- 45 M	T _A = 25 °C	I _R ⁽²⁾	-	9	mA	
	V _R = 45 V	T _A = 125 °C		72	200	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	VT80L45PW	UNIT		
Typical thermal resistance	per diode	- R _{θJC}	0.7	°C/W		
	per device		0.5			
	per device	R _{0JA} ⁽¹⁾⁽²⁾	45			

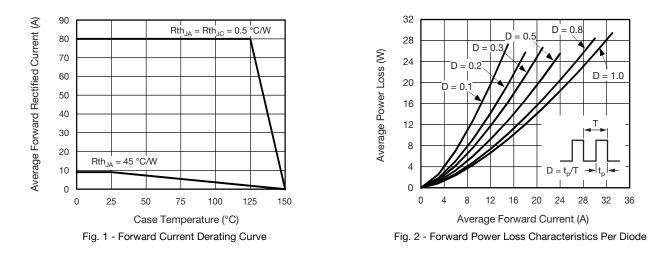
Notes

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{0JA}$

(2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-3PW	VT80L45PW-M3/4W	4.5	4W	30/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)



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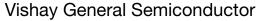


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VT80L45PW



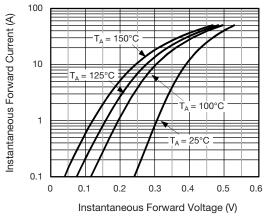
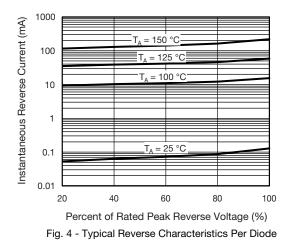
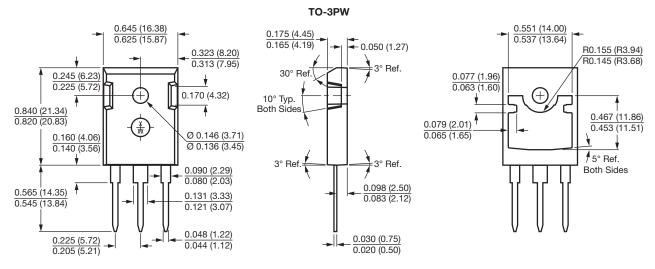


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode





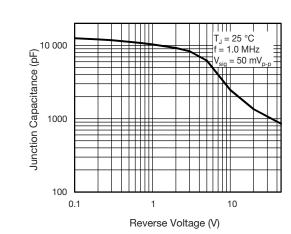


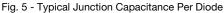
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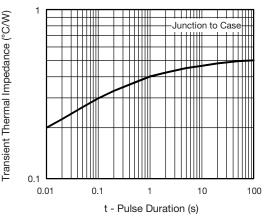


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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